2SC3933

Silicon NPN planer type

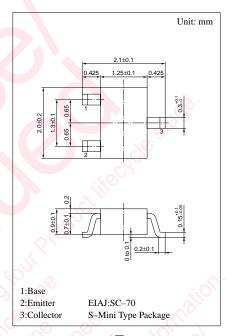
For UHF amplification/mixing

Features

- High power gain PG.
- High transition frequency f_T.
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings Unit	
Collector to base voltage	V_{CBO}	30	V
Collector to emitter voltage	V_{CEO}	20	V
Emitter to base voltage	V_{EBO}	3	V
Collector current	I_{C}	20	mA
Collector power dissipation	P _C	150	mW
Junction temperature	T_{j}	150	°C
Storage temperature	T_{stg}	−55 ~ +150	C C



Marking symbol: 1T

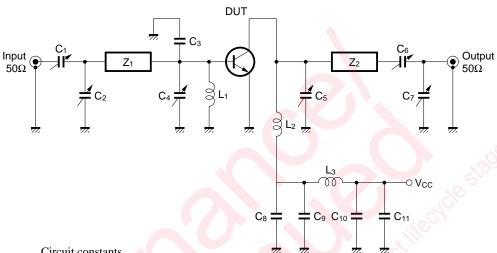
Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 25V, I_{E} = 0$, V.S.		1	μА
Emitter cutoff current	I_{EBO}	$V_{EB} = 3V, I_{C} = 0$	-0		10	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CB} = 10V, I_{E} = -3mA$	40		200	
	h _{FE2}	$V_{CB} = 10V, I_{E} = -10mA$	40		200	
	h _{FE3}	$V_{CB} = 10V, I_E = -100\mu A$	60			
Transition frequency	f_{T}	$V_{CB} = 10V, I_E = -3mA, f = 200MHz$	750	1100	1400	MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		0.7		pF
Common emitter reverse transfer capacitance	C _{rb}	$V_{CB} = 10V, I_E = 0, f = 1MHz$		0.15		pF
Power gain	PG*	$V_{CC} = 11V, V_{AGC} = 3V, f = 800MHz$	14			dB
Noise figure	NF*	$V_{CC} = 11V, V_{AGC} = 3V, f = 800MHz$			5	dB

*PG, NF Refer to the measurment circuit

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The high-frequency output measurment circuit

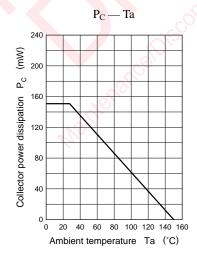


Circuit constants

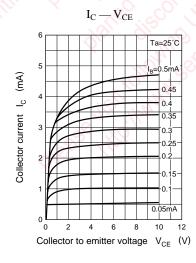
 $C_1, C_2, C_4 \sim C_7 : \sim 20 pF$

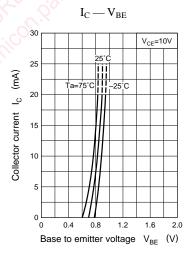
 C_3 : 5pF C₈, C₁₀: 100pF C₉, C₁₁: 1000pF

 $L_1, L_2 : \phi 0.6 \text{mm}$ polyurethane, 2T, D = 5 : ϕ 0.6mm polyurethane, 2T, D = 5 Z_1 : copper board, 2.75mm×20mm : copper board, 2.75mm×20mm \mathbb{Z}_2

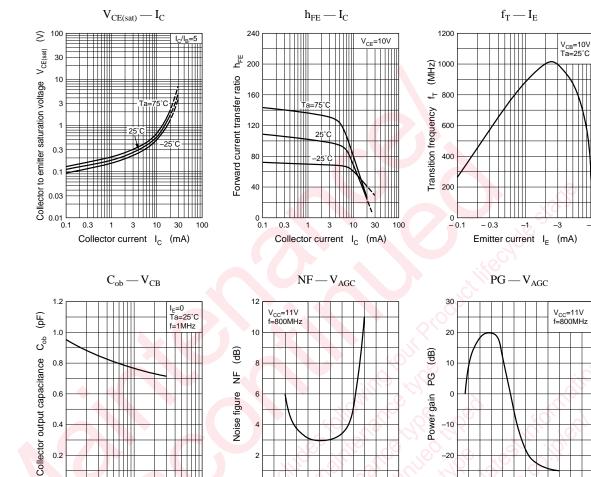


2





Transistor 2SC3933



2

V_{AGC} (V)

0.6

0.4

0.2

3

Collector to base voltage V_{CB} (V)

-10

-20

6

V_{AGC} (V)

10

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